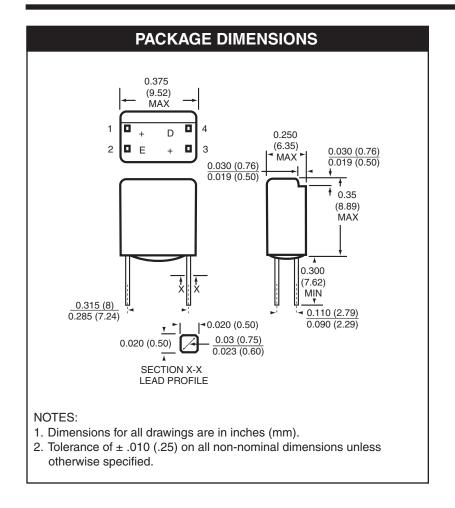
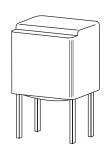
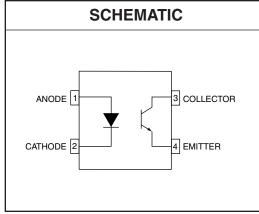
H24A1 H24A2







DESCRIPTION

The H24A series consists of a gallium arsenide infrared emitting diode coupled with a silicon phototransistor. The devices are housed in a low cost plastic package with lead spacing compatible with a dual in line package.

FEATURES

- 4-pin configuration
- · Small package size and low cost
- UL recognized file E50151



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Parameter	Symbol	Rating	Unit	
Operating Temperature	T _{OPR}	-55 to +85	°C	
Storage Temperature	T _{STG}	-55 to +85	°C	
Soldering Temperature (Flow)	T _{SOL-F}	260 for 5 sec	°C	
EMITTER				
Power Dissipation at 25°C Ambient ⁽¹⁾	P _D	100	mW	
Continuous Forward Current	I _F	60	mA	
Reverse Voltage	V _R	4	V	
DETECTOR				
Power Dissipation 25°C Ambient ⁽²⁾	P _D	150	mW	
Collector to Emitter Voltage	V _{CEO}	30	V	
Emitter to Collector Voltage	V _{ECO}	6	V	
Continuous Forward Current	I _C	100	mA	

ELECTRICAL / OPTICAL CHARACTERISTICS (T _A =25°C)								
INDIVIDUAL COMPONENT CHARACTERISTICS								
Parameters	Test Conditions	Symbol	Min	Тур	Max	Units		
EMITTER								
Forward Voltage	I _F = 60 mA	V _F		_	1.7	V		
Reverse Current	V _R = 3.0 V	I _R		_	1	μΑ		
Reverse Breakdown Voltage	I _R = 10 μA	V _{(BR)R}	4			V		
Capacitance	V = 0 V, f = 1 MHz	С		30		pF		
DETECTOR								
Breakdown Voltage Collector to Emitter	$I_C = 1.0 \text{ mA}, I_F = 0$	BV _{CEO}	30			V		
Emitter to Collector	$I_E = 100 \mu A, I_F = 0$	BV _{ECO}	7			V		
Leakage Current Collector to Emitter	V _{CE} = 10 V, I _F = 0	I _{CEO}		5	100	nA		
Capacitance Collector to Emitter	V _{CE} = 5V, f = 1 MHz	C _{CE}		3.3		pF		

NOTE:

- 1. Derate power linearly 1.67 mW/°C above 25°C
- 2. Derate power linearly 2.5 mW/°C above 25°C



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TRANSFER CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)								
DC Characteristics	Test Conditions		Symbol	Min	Тур	Max	Units	
COUPLED	V _{CE} = 10 V, I _F = 10 mA	H24A1	CTR	100			%	
DC current Transfer Ratio (note 1)		H24A2		20			/ /o	
Saturation Voltage	$I_C = 500 \mu A, I_F = 10 \text{mA}$		V _{CE(SAT)}		0.1	0.4	V	
AC Characteristics	Test Conditions		Symbol	Min	Тур	Max	Units	
Turn-on Time	$I_C = 2mA$, $V_{CE} = 10V$ $R_L = 100\Omega$		ton		9		μs	
Turn-off Time			toff		4		μs	
Turn-on Time	$I_F = 10\text{mA}, V_{CC} = 5V$ $R_L = 10\text{k}\Omega$		ton		6.5		μs	
Turn-off Time			toff		165		μs	

ISOLATION CHARACTERISTICS							
Characteristic	Test Conditions	Symbol	Min	Тур	Max	Units	
Surge Isolation Voltage	1 Minute	V _{ISO}	6000			V _{peak}	
Steady-State Isolation Voltage	1 Minute	V _{ISO}	5300			V _{RMS}	
Isolation Resistance	V _{I-0} = 500VDC	R _{ISO}	10 ¹¹			Ohm	
Isolation Capacitance	V _{I-0} = 0, f = 1 MHz	C _{ISO}		0.5		pF	

NOTE:

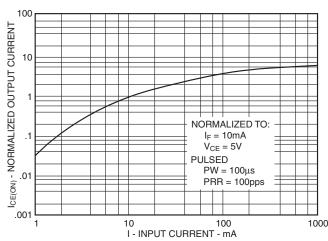
^{1.} The current transfer ratio (I_C/I_F) is the ratio of the detector collector current to the LED input current with V_{CE} at 10 volts.

NORMALIZED TO:

H24A1

PULSED

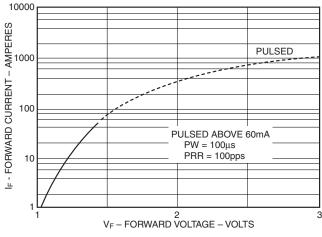
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CE(ON) - NORMALIZED OUTPUT CURRENT $I_F = 10mA$ $PW = 100 \mu s$ $V_{CE} = 5V$ PRR = 100pps $T_A = 25^{\circ}C$ $I_F = 20 \text{mA}$ $I_F = 10mA$ $I_F=5mA$ $I_F = 2mA$.01 0.03 -55 -50 +100 T_A - AMBIENT TEMPERATURE – $^{\circ}C$

Fig. 1. Output Current vs. Input Current

Fig. 2. Output Current vs. Temperature



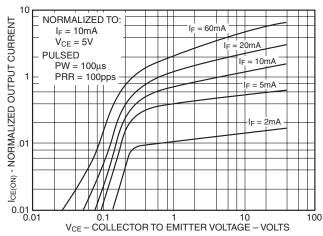
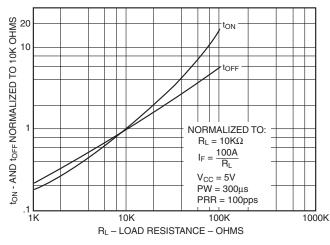


Fig. 3. Input Characteristics

Fig. 4. Output Characteristics



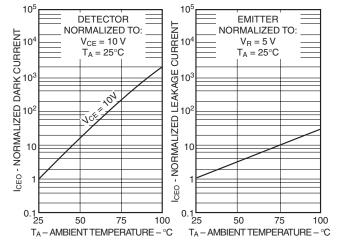


Fig. 5. Switching Speed vs R_L

Fig. 6. Leakage Current vs. Temperature



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